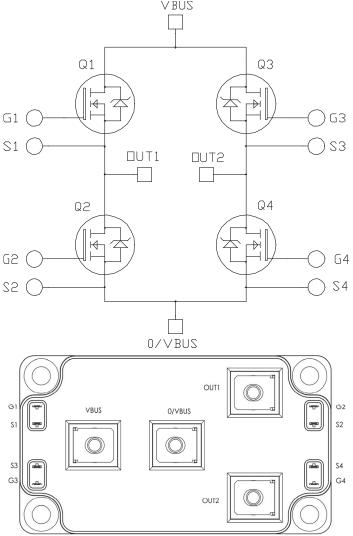
MSCSM120HM083AG

Full Bridge SiC Power Module

Product Overview

The MSCSM120HM083AG device is a full bridge 1200V, 251A silicon carbide (SiC) power module.



Note: All ratings at T_J = 25 °C, unless otherwise specified.

⚠ CAUTION

These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are key features of the MSCSM120HM083AG device:

- SiC Power MOSFET
 - Low R_{DS(on)}
 - High temperature performance
- Kelvin source for easy drive
- Low stray inductance
- M5 power connectors
- Aluminum Nitride (AIN) substrate for improved thermal performance

Benefits

The following are the benefits of MSCSM120HM083AG device:

- High efficiency converter
- Outstanding performance at high frequency operation
- Stable temperature behavior
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS compliant

Application

The MSCSM120HM083AG device is designed for the following applications:

- Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- EV motor and traction drive

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1. Electrical Specifications

This section provides the electrical specifications of the MSCSM120HM083AG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings per SiC MOSFET of the MSCSM120HM083AG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter		Maximum Ratings	Unit	
V _{DSS}	Drain-Source voltage		1200	V	
I _D	Continuous drain current T _C = 25 °C 2		251	Α	
		T _C = 80 °C	200		
I _{DM}	Pulsed drain current		500		
V _{GS}	Gate-Source voltage		-10/23	V	
R _{DS(on)}	Drain-Source ON resistance		10.4	mΩ	
P _D	Power dissipation	T _C = 25 °C	1042	W	

The following table lists the electrical characteristics per SiC MOSFET of the MSCSM120HM083AG device.

Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min.	Тур.	Max.	Unit
I _{DSS}	Zero gate voltage drain current	$V_{GS} = 0V$ $V_{DS} = 1200V$		_	30	300	μΑ
R _{DS(on)}	Drain-Source on	V _{GS} = 20V	T _J = 25 °C	_	8.4	10.4	mΩ
resistance $I_D = 1$	I _D = 120A	T _J = 175 °C	_	13.4	_		
V _{GS(th)}	Gate threshold voltage	$V_{GS} = V_{DS}$ $I_D = 9 \text{ mA}$		1.8	2.8	_	V
I _{GSS}	Gate–Source leakage current	$V_{GS} = 20V$; $V_{DS} = 0V$		_	_	300	nA

The following table lists the dynamic characteristics per SiC MOSFET of the MSCSM120HM083AG device.

Table 1-3. Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min.	Тур.	Max.	Unit
C _{iss}	Input capacitance	V _{GS} = 0V		_	9	_	nF
C _{oss}	Output capacitance	V _{DS} = 1000V		_	0.81	_	
C _{rss}	Reverse transfer capacitance	f = 1 MHz		_	0.07	_	
Qg	Total gate charge	V _{GS} = -5V/20V		_	696	_	nC
Q _{gs}	Gate-Source charge	V _{Bus} = 800V		_	123	_	
Q_{gd}	Gate-Drain charge	I _D = 120A		_	150	_	
T _{d(on)}	Turn-on delay time	$V_{GS} = -5V/20V$ $V_{Bus} = 600V$ $I_{D} = 150A$ $R_{G(on)} = 9.4\Omega$ $R_{G(off)} = 3.6\Omega$	T _J = 150 °C	_	66	_	ns
T _r	Rise time			_	74	_	
T _{d(off)}	Turn-off delay time			_	166	_	
T _f	Fall time				67	_	
Eon	Turn-on energy	V _{GS} = -5V/20V	T _J = 150 °C	_	4.8	_	mJ
E _{off}	Turn-off energy	$V_{Bus} = 600V$ $I_D = 150A$ $R_{G(on)} = 9.4\Omega$ $R_{G(off)} = 3.6\Omega$		_	2.2	_	
R _{Gint}	Internal gate resistance			_	2	_	Ω
R _{thJC}	Junction-to-case thermal resistance			_	_	0.144	°C/W

The following table lists the body diode ratings and characteristics per SiC MOSFET of the MSCSM120HM083AG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min.	Тур.	Max.	Unit
V _{SD}	Diode forward voltage	$V_{GS} = 0V; I_{SD} = 120A$	_	4	_	V
		$V_{GS} = -5V$; $I_{SD} = 120A$	_	4.2	_	
t _{rr}	Reverse recovery time	$I_{SD} = 120A; V_{GS} = -5V$	_	90	_	ns
Q _{rr}	Reverse recovery charge	$V_R = 800V$; $di_F/dt = 3000 A/\mu s$	_	1650	_	nC
I _{rr}	Reverse recovery current		_	41	_	Α

1.2 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCSM120HM083AG device.

Table 1-5. Thermal and Package Characteristics

Symbol	Characteristics			Min.	Max.	Unit
V _{ISOL}	RMS isolation voltage, any terminal to case t = 1 min, 50 Hz/60 Hz			4000	_	V
T _J	Operating junction temperature range				175	°C
T _{JOP}	Recommended junction temperature under switching conditions			-40	T _{Jmax} –25	
T _{STG}	Storage temperature range				125	
T _C	Operating case temperature			-40	125	
Torque	Mounting torque	To heatsink	M6	3	5	N.m
	For terminals M5				3.5	
Wt	Package weight			_	300	g

1.3 Typical SiC MOSFET Performance Curve

This section shows the typical SiC MOSFET performance curves of the MSCSM120HM083AG device.

Figure 1-1. Maximum Thermal Impedance

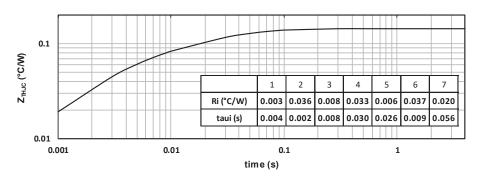


Figure 1-2. Output Characteristics, $T_J = 25$ °C

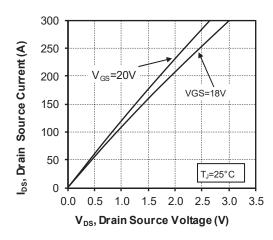


Figure 1-3. Output Characteristics, T_J = 175 °C

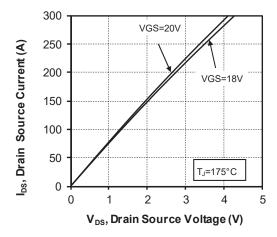


Figure 1-4. Normalized R_{DS(on)} vs. Temperature

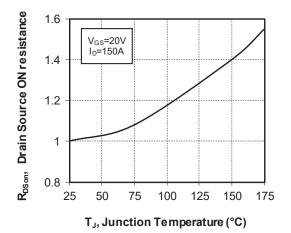


Figure 1-5. Transfer Characteristics

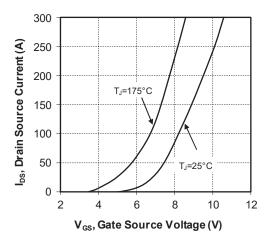


Figure 1-6. Switching Energy vs. Current

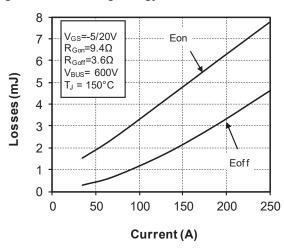


Figure 1-7. Switching Energy vs. Rg

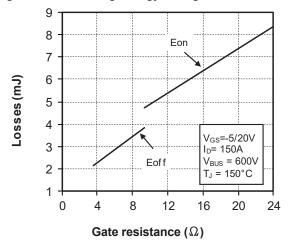


Figure 1-8. Capacitance vs. Drain Source Voltage

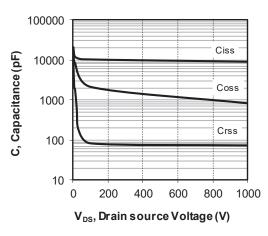


Figure 1-9. Gate Charge vs. Gate Source Voltage

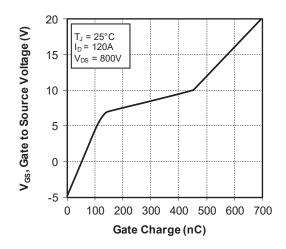
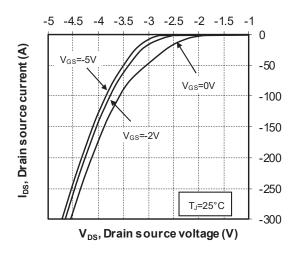


Figure 1-10. Body Diode Characteristics, T_J = 25 °C Figure 1-11. 3^{rd} Quadrant Characteristics, T_J = 25 °C



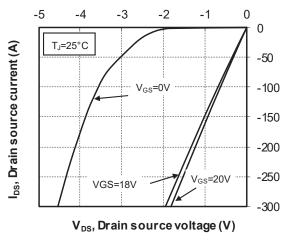
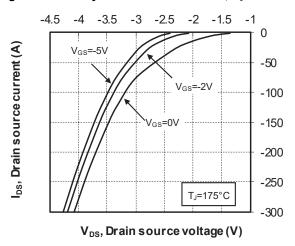


Figure 1-12. Body Diode Characteristics, T_J = 175 °C Figure 1-13. 3rd Quadrant Characteristics, T_J = 175 °C



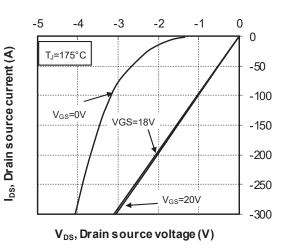
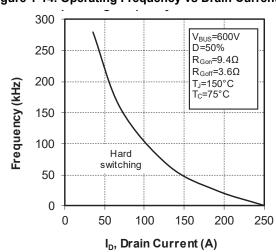


Figure 1-14. Operating Frequency vs Drain Current



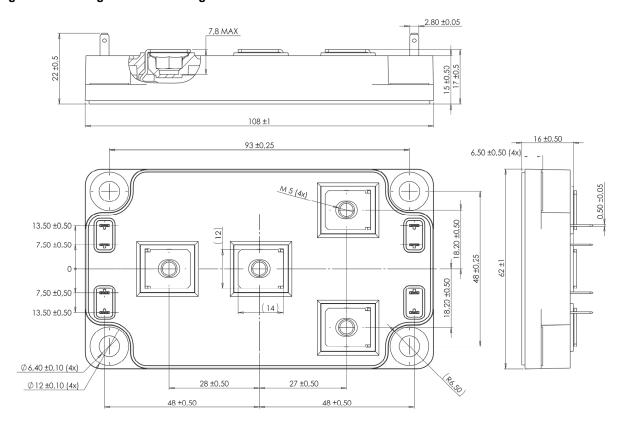
2. Package Specifications

The following section shows the package specification of the MSCSM120HM083AG device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM120HM083AG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Note: See APT0601—Mounting Instructions for SP6 Power Modules for more information.

MSCSM120HM083AG

Revision History

3. Revision History

Revision	Date	Description
Α	06/2022	Initial Release

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